BTA410X-600CT



3Q Hi-Com Triac Rev. 1 — 13 March 2012

Product data sheet

Product profile 1.

1.1 General description

Planar passivated high commutation three quadrant triac in a SOT186A (TO-220F) "full pack" plastic package intended for use in circuits where high static and dynamic dV/dt and high dl/dt can occur. This "series CT" triac will commutate the full RMS current at the maximum rated junction temperature ($T_{i(max)} = 150$ °C) without the aid of a snubber. It is used in applications where "high junction operating temperature capability" is required.

1.2 Features and benefits

- 3Q technology for improved noise immunity
- High commutation capability with maximum false trigger immunity
- High immunity to false turn-on by dV/dt
- High junction operating temperature capability
- High voltage capability
- Isolated mounting base package
- Less sensitive gate for high noise immunity
- Planar passivated for voltage ruggedness and reliability
- Triggering in three quadrants only

1.3 Applications

- Applications subject to high temperature
- Industrial and domestic heating circuits
- Motor controls e.g. washing machines and vacuum cleaners
- Rectifier-fed DC inductive loads e.g. DC motors and solenoids

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{DRM}	repetitive peak off-state voltage		-	-	600	V
I _{TSM}	non-repetitive peak on-state current	full sine wave; $T_{j(init)} = 25 ^{\circ}\text{C}$; $t_p = 20 \text{ms}$; see <u>Figure 4</u> ; see <u>Figure 5</u>	-	-	100	Α
Tj	junction temperature		-	-	150	°C
I _{T(RMS)}	RMS on-state current	full sine wave; $T_h \le 98 ^{\circ}\text{C}$; see Figure 1; see Figure 2; see Figure 3	-	-	10	Α



Table 1. Quick reference data ... continued

Min 2	Тур	Max	Unit							
2										
2			Static characteristics							
	-	35	mA							
2	-	35	mA							
2	-	35	mA							
% 500 e	-	-	V/µs							
A; 8	-	-	A/ms							
E	2 % 500	2 - % 500 -	2 - 35							

2. Pinning information

Table 2. Pinning information

	~	,		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	T1	main terminal 1		N 1
2	T2	main terminal 2	mb	T2—T1
3	G	gate		`G sym051
	n.c.	mounting base; isolated		
			SOT186A (TO-220F)	

3. Ordering information

Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
BTA410X-600CT	TO-220F	plastic single-ended package; isolated heatsink mounted; 1 mounting hole; 3-lead TO-220 "full pack"	SOT186A		

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DRM}	repetitive peak off-state voltage		-	600	V
I _{T(RMS)}	RMS on-state current	full sine wave; $T_h \le 98$ °C; see <u>Figure 1</u> ; see <u>Figure 2</u> ; see <u>Figure 3</u>	-	10	Α
I _{TSM}	non-repetitive peak on-state current	full sine wave; $T_{j(init)} = 25 \text{ °C}$; $t_p = 20 \text{ ms}$; see <u>Figure 4</u> ; see <u>Figure 5</u>	-	100	Α
		full sine wave; $T_{j(init)} = 25$ °C; $t_p = 16.7$ ms	-	110	Α
I ² t	I ² t for fusing	t _p = 10 ms; sine-wave pulse	-	50	A ² s
dI _T /dt	rate of rise of on-state current	$I_T = 20 \text{ A}; I_G = 0.2 \text{ A}; dI_G/dt = 0.2 \text{ A}/\mu\text{s}$	-	100	A/μs
I _{GM}	peak gate current		-	2	Α
P_{GM}	peak gate power		-	5	W
$P_{G(AV)}$	average gate power	over any 20 ms period	-	0.5	W
T _{stg}	storage temperature		-40	150	°C
T _j	junction temperature		-	150	°C

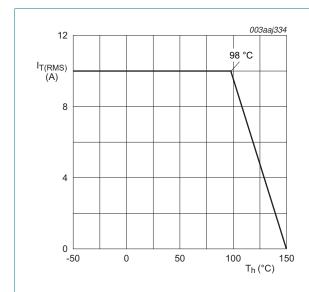
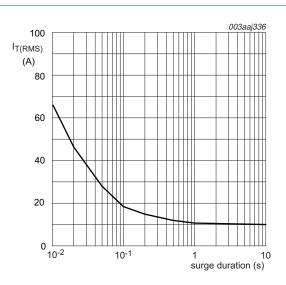


Fig 1. RMS on-state current as a function of heatsink temperature; maximum values



 $f = 50 \text{ Hz}; T_h = 98 \degree \text{C}$

Fig 2. RMS on-state current as a function of surge duration; maximum values

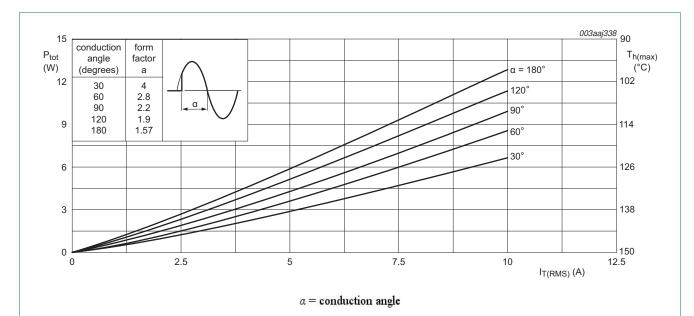


Fig 3. Total power dissipation as a function of RMS on-state current; maximum values

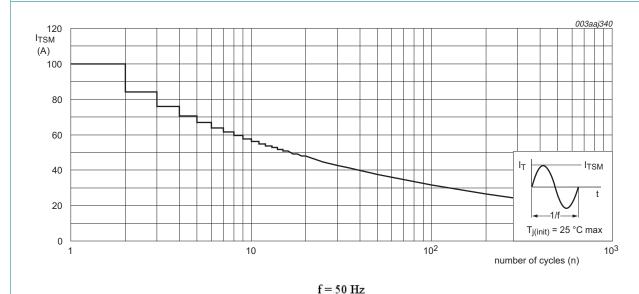
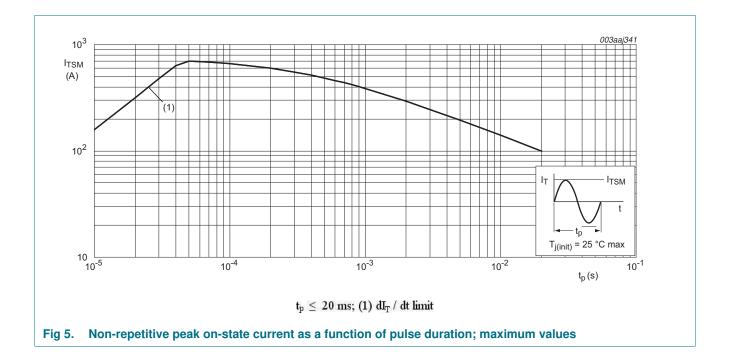


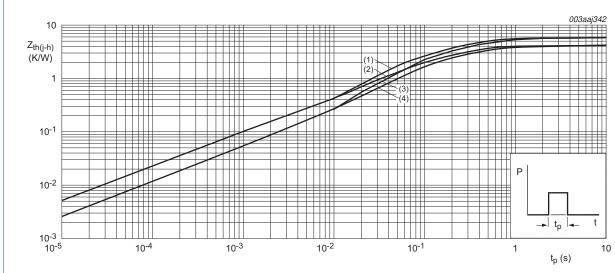
Fig 4. Non-repetitive peak on-state current as a function of the number of sinusoidal current cycles; maximum values



5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-h)}$	thermal resistance from junction to heatsink	full cycle or half cycle; with heatsink compound; see Figure 6	-	-	4	K/W
		full cycle or half cycle; without heatsink compound; see Figure 6	-	-	5.5	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	-	55	-	K/W



- (1) Unidirectional (half cycle) without heatsink compound
- (2) Unidirectional (half cycle) with heatsink compound
- (3) Bidirectional (full cycle) without heatsink compound
- (4) Bidirectional (full cycle) with heatsink compound

Fig 6. Transient thermal impedance from junction to heatsink as a function of pulse duration

6. Isolation characteristics

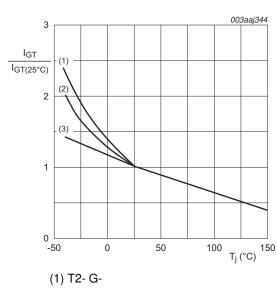
Table 6. Isolation characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{\text{isol}(\text{RMS})}$	RMS isolation voltage	from all terminals to external heatsink; sinusoidal waveform; clean and dust free ; $50 \text{ Hz} \le f \le 60 \text{ Hz}$; RH $\le 65 \%$; T _h = 25 °C	-	-	2500	V
C _{isol}	isolation capacitance	from main terminal 2 to external heatsink ; $f = 1 \text{ MHz}$; $T_h = 25 ^{\circ}\text{C}$	-	10	-	pF

7. Characteristics

Table 7. Characteristics

Table 1.	Characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics					
I _{GT}	gate trigger current	$V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; T2+ G-; T_j = 25 ^{\circ}C;$ see Figure 7	2	-	35	mA
		$V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; T2+G+; T_j = 25 ^{\circ}\text{C};$ see Figure 7	2	-	35	mA
		$V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; T2- \text{G-}; T_j = 25 \text{ °C};$ see Figure 7	2	-	35	mA
I _L latching current	$V_D = 12 \text{ V}; I_G = 0.1 \text{ A}; T2+ G+;$ $T_j = 25 \text{ °C}; \text{ see } \frac{\text{Figure 8}}{}$	-	-	50	mA	
		$V_D = 12 \text{ V}; I_G = 0.1 \text{ A}; T2+G-; T_j = 25 ^{\circ}\text{C};$ see Figure 8	-	-	60	mA
	$V_D = 12 \text{ V}; I_G = 0.1 \text{ A}; \text{T2- G-}; T_j = 25 \text{ °C};$ see Figure 8	-	-	50	mA	
I _H	holding current	$V_D = 12 \text{ V; } T_j = 25 \text{ °C; see } \frac{\text{Figure 9}}{\text{ or } 100 \text{ J}}$	-	-	35	mA
V_{T}	on-state voltage	I _T = 15 A; T _j = 25 °C; see <u>Figure 10</u>	-	1.3	1.6	٧
V _{GT}	gate trigger voltage	$V_D = 12 \text{ V; } T_j = 25 \text{ °C; see } \frac{\text{Figure } 11}{}$	-	8.0	1.5	V
		V _D = 400 V; T _j = 150 °C; see <u>Figure 11</u>	0.25	0.4	-	V
I _D	off-state current	V _D = 600 V; T _j = 150 °C	-	0.4	2	mA
Dynamic (characteristics					
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 402 V; T_{j} = 150 °C; (V $_{DM}$ = 67% of V $_{DRM}$); exponential waveform; gate open circuit	500	-	-	V/µs
	rate of change of commutating current	$\begin{split} V_D &= 400 \text{ V; } T_j = 150 \text{ °C; } I_{T(RMS)} = 10 \text{ A;} \\ dV_{com}/dt &= 20 \text{ V/}\mu\text{s; } (\text{snubberless} \\ \text{condition); } \text{gate open circuit} \end{split}$	8	-	-	A/ms
		$V_D = 400 \text{ V}; T_j = 150 \text{ °C}; I_{T(RMS)} = 10 \text{ A};$ $dV_{com}/dt = 10 \text{ V/}\mu\text{s};$ gate open circuit	13	-	-	A/ms
		$V_D = 400 \text{ V}; T_j = 150 \text{ °C}; I_{T(RMS)} = 10 \text{ A};$ $dV_{com}/dt = 1 \text{ V}/\mu s;$ gate open circuit	20	-	-	A/ms



- (2) T2+ G-
- (3) T2+ G+

Fig 7. Normalized gate trigger current as a function of junction temperature

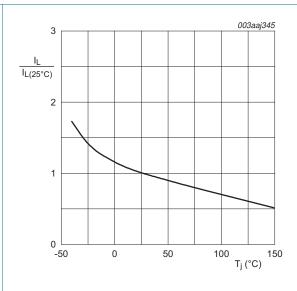
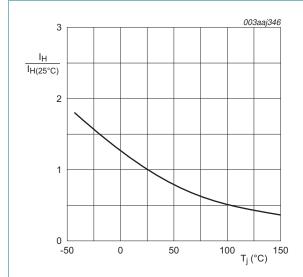
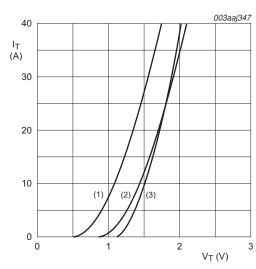


Fig 8. Normalized latching current as a function of junction temperature



Normalized holding current as a function of Fig 9. junction temperature



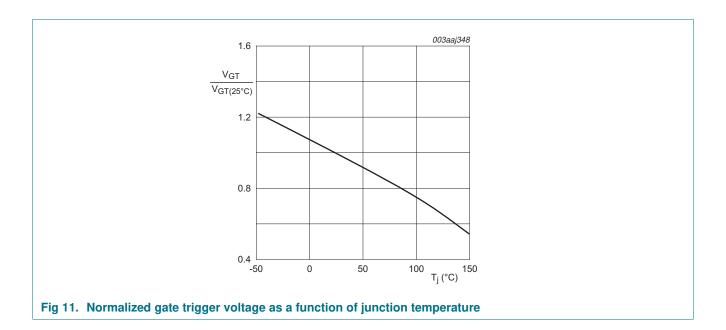
Vo = 1.142 V; $Rs = 0.027 \Omega$

(1) Tj = 150 °C; typical values

(2) Tj = 150 °C; maximum values

(3) Tj = 25 °C; maximum values

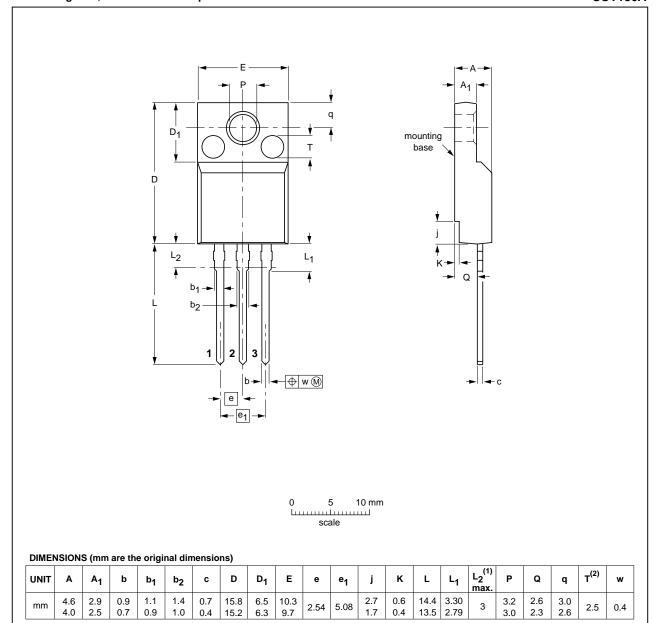
Fig 10. On-state current as a function of on-state voltage



8. Package outline

Plastic single-ended package; isolated heatsink mounted; 1 mounting hole; 3-lead TO-220 'full pack'

SOT186A



Notes

- 1. Terminal dimensions within this zone are uncontrolled.
- 2. Both recesses are \varnothing 2.5 \times 0.8 max. depth

OUTLINE	REFERENCES			EUROPEAN	ISSUE DATE	
VERSION	IEC	IEC JEDEC JEIT.			PROJECTION	1330E DATE
SOT186A		3-lead TO-220F				-02-04-09 06-02-14

Fig 12. Package outline SOT186A (TO-220F)

BTA410X-600CT

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9. Revision history

Table 8. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BTA410X-600CT v.1	20120313	Product data sheet	-	-

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10.1 Data sheet status

Document status[1] [2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

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12. Contents

1	Product profile
1.1	General description1
1.2	Features and benefits1
1.3	Applications1
1.4	Quick reference data1
2	Pinning information2
3	Ordering information2
4	Limiting values3
5	Thermal characteristics6
6	Isolation characteristics 6
7	Characteristics7
8	Package outline10
9	Revision history11
10	Legal information12
10.1	Data sheet status
10.2	Definitions12
10.3	Disclaimers
10.4	Trademarks13
11	Contact information13

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